NSN 5961-00-152-8520

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View Online at https://aerobasegroup.com/nsn/5961-00-152-8520	
Inclosure Material:	
Metal	
Overall Length:	
Between 0.245 inches and 0.295 inches	
Mounting Facility Quantity:	
1	
Internal Configuration:	
Junction contact	
Mounting Method:	
Threaded stud	
Features Provided:	
Hermetically sealed case	
Overall Width Across Flats:	
Between 0.420 inches and 0.440 inches	
Thread Size:	
0.190 inches	
Semiconductor Material:	
Silicon	
Voltage Rating In Volts Per Characteristic:	
65.0 collector to base voltage/static/emitter open and 41.0 collector to emitter voltage/static/base open and 4.0 emitter to base voltage,	
static, collector open	
Current Rating Per Characteristic:	
1.50 amperes source cutoff current	
Power Rating Per Characteristic:	
2.6 watts small-signal input power, common-collector preset	
Maximum Operating Tempurature Per Measurement Point:	
200.0 degrees celsius junction	
Special Features:	
Junction pattern arrangement: npn	
Test Data Document:	
81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification	
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain	
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).	
Thread Series Designator:	
Unf	
Terminal Type And Quantity:	
3 pin	
Specification Data:	
81349-mil-s-19500/341 government specification	
Shelf Life:	
N/a	
Unit Of Measure:	

N

Demilitarization:

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